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Applications of "<u>Embedded - Microcontrollers</u>"

Data ila	
Details	
Product Status	Active
Core Processor	R8C
Core Size	16-Bit
Speed	20MHz
Connectivity	I ² C, LINbus, SIO, SSU, UART/USART
Peripherals	LED, POR, Voltage Detect, WDT
Number of I/O	25
Program Memory Size	16KB (16K x 8)
Program Memory Type	FLASH
EEPROM Size	-
RAM Size	1K x 8
Voltage - Supply (Vcc/Vdd)	2.2V ~ 5.5V
Data Converters	A/D 12x10b
Oscillator Type	Internal
Operating Temperature	-40°C ~ 85°C (TA)
Mounting Type	Surface Mount
Package / Case	32-LQFP
Supplier Device Package	32-LQFP (7x7)
Purchase URL	https://www.e-xfl.com/product-detail/renesas-electronics-america/r5f21264sdfp-x6

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Address: Room A, 16/F, Full Win Commercial Centre, 573 Nathan Road, Mongkok, Hong Kong

Table 1.4 **Product Information for R8C/27 Group**

Current of Sep. 2008

	ROM (Capacity	RAM			
Part No.	Program ROM	Data flash	Capacity	Package Type	Re	marks
R5F21272SNFP	8 Kbytes	1 Kbyte x 2	512 bytes	PLQP0032GB-A	N version	
R5F21274SNFP	16 Kbytes	1 Kbyte × 2	1 Kbyte	PLQP0032GB-A		
R5F21275SNFP	24 Kbytes	1 Kbyte × 2	1.5 Kbytes	PLQP0032GB-A		
R5F21276SNFP	32 Kbytes	1 Kbyte × 2	1.5 Kbytes	PLQP0032GB-A		
R5F21272SDFP	8 Kbytes	1 Kbyte × 2	512 bytes	PLQP0032GB-A	D version	
R5F21274SDFP	16 Kbytes	1 Kbyte × 2	1 Kbyte	PLQP0032GB-A		
R5F21275SDFP	24 Kbytes	1 Kbyte × 2	1.5 Kbytes	PLQP0032GB-A		
R5F21276SDFP	32 Kbytes	1 Kbyte × 2	1.5 Kbytes	PLQP0032GB-A		
R5F21274JFP	16 Kbytes	1 Kbyte × 2	1 Kbyte	PLQP0032GB-A	J version	
R5F21276JFP	32 Kbytes	1 Kbyte × 2	1.5 Kbytes	PLQP0032GB-A		
R5F21274KFP	16 Kbytes	1 Kbyte × 2	1 Kbyte	PLQP0032GB-A	K version	
R5F21276KFP	32 Kbytes	1 Kbyte × 2	1.5 Kbytes	PLQP0032GB-A		
R5F21272SNXXXFP	8 Kbytes	1 Kbyte × 2	512 bytes	PLQP0032GB-A	N version	Factory
R5F21274SNXXXFP	16 Kbytes	1 Kbyte × 2	1 Kbyte	PLQP0032GB-A		programming
R5F21275SNXXXFP	24 Kbytes	1 Kbyte x 2	1.5 Kbytes	PLQP0032GB-A		product ⁽¹⁾
R5F21276SNXXXFP	32 Kbytes	1 Kbyte × 2	1.5 Kbytes	PLQP0032GB-A		
R5F21272SDXXXFP	8 Kbytes	1 Kbyte × 2	512 bytes	PLQP0032GB-A	D version	
R5F21274SDXXXFP	16 Kbytes	1 Kbyte × 2	1 Kbyte	PLQP0032GB-A		
R5F21275SDXXXFP	24 Kbytes	1 Kbyte × 2	1.5 Kbytes	PLQP0032GB-A		
R5F21276SDXXXFP	32 Kbytes	1 Kbyte × 2	1.5 Kbytes	PLQP0032GB-A		
R5F21274JXXXFP	16 Kbytes	1 Kbyte × 2	1 Kbyte	PLQP0032GB-A	J version	
R5F21276JXXXFP	32 Kbytes	1 Kbyte x 2	1.5 Kbytes	PLQP0032GB-A		
R5F21274KXXXFP	16 Kbytes	1 Kbyte x 2	1 Kbyte	PLQP0032GB-A	K version]
R5F21276KXXXFP	32 Kbytes	1 Kbyte x 2	1.5 Kbytes	PLQP0032GB-A		

^{1.} The user ROM is programmed before shipment.

1.5 Pin Assignments

Figure 1.4 shows Pin Assignments (Top View).

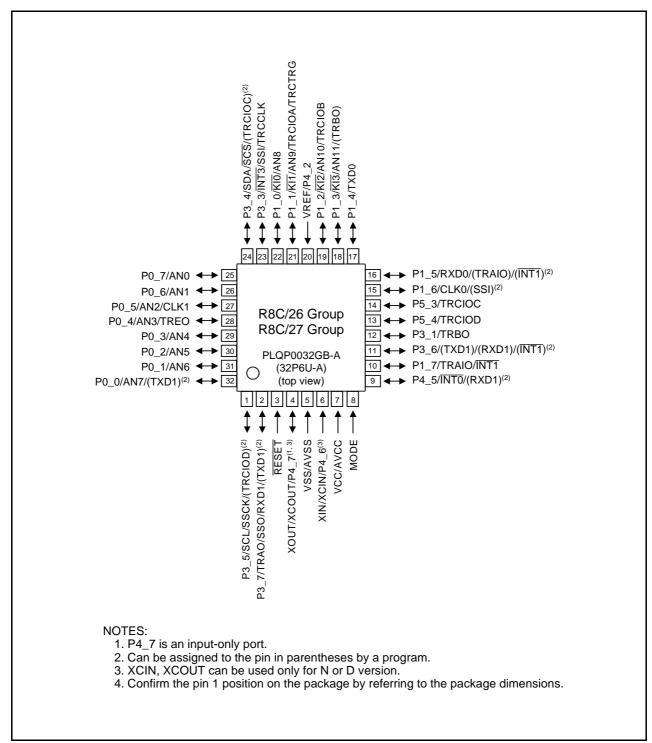


Figure 1.4 Pin Assignments (Top View)

1.6 Pin Functions

Table 1.5 lists Pin Functions.

Table 1.5 Pin Functions

Туре	Symbol	I/O Type	Description
Power supply input	VCC, VSS	I	Apply 2.2 to 5.5 V (J, K version are 2.7 to 5.5 V) to the VCC pin. Apply 0 V to the VSS pin.
Analog power supply input	AVCC, AVSS	I	Power supply for the A/D converter. Connect a capacitor between AVCC and AVSS.
Reset input	RESET	I	Input "L" on this pin resets the MCU.
MODE	MODE	I	Connect this pin to VCC via a resistor.
XIN clock input	XIN	I	These pins are provided for XIN clock generation circuit I/O. Connect a ceramic resonator or a crystal oscillator between the
XIN clock output	XOUT	0	XIN and XOUT pins. To use an external clock, input it to the XIN pin and leave the XOUT pin open.
XCIN clock input (N, D version)	XCIN	I	These pins are provided for XCIN clock generation circuit I/O. Connect a crystal oscillator between the XCIN and XCOUT
XCIN clock output (N, D version)	XCOUT	0	pins. To use an external clock, input it to the XCIN pin and leave the XCOUT pin open.
INT interrupt input	INTO, INT1, INT3	I	INT interrupt input pins
Key input interrupt	KIO to KI3	I	Key input interrupt input pins
Timer RA	TRAO	0	Timer RA output pin
	TRAIO	I/O	Timer RA I/O pin
Timer RB	TRBO	0	Timer RB output pin
Timer RC	TRCCLK	I	External clock input pin
	TRCTRG	I	External trigger input pin
	TRCIOA, TRCIOB, TRCIOC, TRCIOD	I/O	Sharing output-compare output / input-capture input / PWM / PWM2 output pins
Timer RE	TREO	0	Timer RE output pin
Serial interface	CLK0, CLK1	I/O	Clock I/O pin
	RXD0, RXD1	I	Receive data input pin
	TXD0, TXD1	0	Transmit data output pin
I ² C bus interface	SCL	I/O	Clock I/O pin
	SDA	I/O	Data I/O pin
Clock synchronous	SSI	I/O	Data I/O pin
serial I/O with chip	SCS	I/O	Chip-select signal I/O pin
select	SSCK	I/O	Clock I/O pin
	SSO	I/O	Data I/O pin
Reference voltage input	VREF	I	Reference voltage input pin to A/D converter
A/D converter	AN0 to AN11	I	Analog input pins to A/D converter
I/O port	P0_0 to P0_7, P1_0 to P1_7, P3_1, P3_3 to P3_7, P4_5, P5_3, P5_4	I/O	CMOS I/O ports. Each port has an I/O select direction register, allowing each pin in the port to be directed for input or output individually. Any port set to input can be set to use a pull-up resistor or not by a program. P1_0 to P1_7 also function as LED drive ports (N, D version).
Input port	P4_2, P4_6, P4_7	I	Input-only ports
			1

I: Input

O: Output

I/O: Input and output



Table 4.2 SFR Information (2)⁽¹⁾

Address	Register	Symbol	After reset
0030h			
0031h	Voltage Detection Register 1 (2)	VCA1	00001000b
0032h	Voltage Detection Register 2 (2)	VCA2	• N, D version 00h ⁽³⁾
	Tomago Dotosion Hogisto. 2		00100000b ⁽⁴⁾
			• J, K version 00h ⁽⁷⁾
			01000000b ⁽⁸⁾
00001			0100000b(°)
0033h			
0034h			
0035h	N 1	1,0046	N. D
0036h	Voltage Monitor 1 Circuit Control Register (5)	VW1C	• N, D version 00001000b
			• J, K version 0000X000b ⁽⁷⁾
			0100X001b ⁽⁸⁾
0037h	Voltage Monitor 2 Circuit Control Register (5)	VW2C	00h
0038h	Voltage Monitor 0 Circuit Control Register (6)	VW0C	0000X000b ⁽³⁾
			0100X001b ⁽⁴⁾
0039h			
	I	L	
003Fh			
0040h			
0041h			
0042h			
0043h			
0044h			
0045h			
0046h			
0047h	Timer RC Interrupt Control Register	TRCIC	XXXXX000b
0047H	Timer No Interrupt Control Negister	TROIC	70000000
0049h			
0043h	Timer RE Interrupt Control Register	TREIC	XXXXX000b
004An	Timer NE Interrupt Control Negister	TREIC	XXXXXXXXXXXXXXXXXXXXXXXXXXXXXXXXXXXXXXX
004Bh			
004CH	Key Input Interrupt Control Register	KUPIC	XXXXX000b
004Bh	A/D Conversion Interrupt Control Register	ADIC	XXXXX000b
004En		SSUIC/IICIC	XXXXX000b
	SSU/IIC bus Interrupt Control Register ⁽⁹⁾	33010/11010	**************************************
0050h	LIADTO Too a social latera and Control Descietos	COTIC	VVVVV000b
0051h	UARTO Transmit Interrupt Control Register	SOTIC	XXXXX000b
0052h	UARTO Receive Interrupt Control Register	SORIC	XXXXX000b
0053h	UART1 Transmit Interrupt Control Register	S1TIC	XXXXX000b
0054h	UART1 Receive Interrupt Control Register	S1RIC	XXXXX000b
0055h			Lyana a sa
0056h	Timer RA Interrupt Control Register	TRAIC	XXXXX000b
0057h			
0058h	Timer RB Interrupt Control Register	TRBIC	XXXXX000b
0059h	INT1 Interrupt Control Register	INT1IC	XX00X000b
005Ah	INT3 Interrupt Control Register	INT3IC	XX00X000b
005Bh			
005Ch	I I I I I I I I I I I I I I I I I I I		
005Dh	INT0 Interrupt Control Register	INTOIC	XX00X000b
005Eh			
005Fh			
0060h			
	1		
006Fh			
0070h			
	_		
007Fh			
X: Undefined			

- 1. The blank regions are reserved. Do not access locations in these regions.
- 2. (N, D version) Software reset, watchdog timer reset, voltage monitor 1 reset, or voltage monitor 2 reset do not affect this register. (J, K version) Software reset, watchdog timer reset, or voltage monitor 2 reset do not affect this register.
- 3. The LVD0ON bit in the OFS register is set to 1 and hardware reset.
- 4. Power-on reset, voltage monitor 0 reset or the LVD0ON bit in the OFS register is set to 0, and hardware reset.
- 5. (N, D version) Software reset, watchdog timer reset, voltage monitor 1 reset, or voltage monitor 2 reset do not affect b2 and b3. (J, K version) Software reset, watchdog timer reset, or voltage monitor 2 reset do not affect b2 and b3.
- 6. (N, D version) Software reset, watchdog timer reset, voltage monitor 1 reset, or voltage monitor 2 reset do not affect this register. (J, K version) These regions are reserved. Do not access locations in these regions.
- 7. The LVD1ON bit in the OFS register is set to 1 and hardware reset.
- 8. Power-on reset, voltage monitor 1 reset, or the LVD10N bit in the OFS register is set to 0 and hardware reset.
- 9. Selected by the IICSEL bit in the PMR register.



Table 4.6 SFR Information (6)⁽¹⁾

Address	Register	Symbol	After reset
0140h	-5	-,	
0141h			
0142h			
0143h			
0144h			
0145h			
0146h			
0147h			
0148h			
0149h			
014Ah			
014Bh			
014Ch			
014Dh			
014Eh			
014Fh			
0150h			
0150h			
0151h			
0152h			
0153fi 0154h			
0154H			
0155h			
0156fi 0157h			
0157h 0158h			
0159h			
015Ah 015Bh			
015Ch			
015Dh			
015Eh			
015Fh			
0160h			
0161h			
0162h			
0163h			
0164h			
0165h			
0166h			
0167h			
0168h			
0169h			
016Ah			
016Bh			
016Ch			
016Dh			
016Eh			
016Fh			
0170h			
0171h			
0172h			
0173h			
0174h			
0175h			
0176h			
0177h			
0178h			
0179h			
017Ah			
017Bh			
017Ch			
017Dh			
017Eh			
017Fh			
NOTE:			

NOTE

1. The blank regions are reserved. Do not access locations in these regions.

Table 5.5 Flash Memory (Data flash Block A, Block B) Electrical Characteristics⁽⁴⁾

Symbol	Parameter	Conditions		Unit		
Symbol	Farameter	Conditions	Min.	n. Typ. Max.		Offic
=	Program/erase endurance ⁽²⁾		10,000(3)	-	_	times
_	Byte program time (program/erase endurance ≤ 1,000 times)		-	50	400	μS
_	Byte program time (program/erase endurance > 1,000 times)		-	65	_	μS
_	Block erase time (program/erase endurance ≤ 1,000 times)		-	0.2	9	S
_	Block erase time (program/erase endurance > 1,000 times)		-	0.3	_	S
td(SR-SUS)	Time delay from suspend request until suspend		-	-	97 + CPU clock × 6 cycles	μS
_	Interval from erase start/restart until following suspend request		650	=	_	μS
_	Interval from program start/restart until following suspend request		0	-	_	ns
=	Time from suspend until program/erase restart		-	-	3 + CPU clock × 4 cycles	μS
=	Program, erase voltage		2.7	-	5.5	V
=	Read voltage		2.2	-	5.5	V
-	Program, erase temperature		-20 ⁽⁸⁾	_	85	°C
_	Data hold time ⁽⁹⁾	Ambient temperature = 55°C	20	_	_	year

- 1. Vcc = 2.7 to 5.5 V at Topr = -20 to 85°C (N version) / -40 to 85°C (D version), unless otherwise specified.
- 2. Definition of programming/erasure endurance
 - The programming and erasure endurance is defined on a per-block basis.

If the programming and erasure endurance is n (n = 10,000), each block can be erased n times. For example, if 1,024 1-byte writes are performed to different addresses in block A, a 1 Kbyte block, and then the block is erased, the programming/erasure endurance still stands at one.

However, the same address must not be programmed more than once per erase operation (overwriting prohibited).

- 3. Endurance to guarantee all electrical characteristics after program and erase. (1 to Min. value can be guaranteed).
- 4. Standard of block A and block B when program and erase endurance exceeds 1,000 times. Byte program time to 1,000 times is the same as that in program ROM.
- 5. In a system that executes multiple programming operations, the actual erasure count can be reduced by writing to sequential addresses in turn so that as much of the block as possible is used up before performing an erase operation. For example, when programming groups of 16 bytes, the effective number of rewrites can be minimized by programming up to 128 groups before erasing them all in one operation. In addition, averaging the erasure endurance between blocks A and B can further reduce the actual erasure endurance. It is also advisable to retain data on the erasure endurance of each block and limit the number of erase operations to a certain number.
- 6. If an error occurs during block erase, attempt to execute the clear status register command, then execute the block erase command at least three times until the erase error does not occur.
- 7. Customers desiring program/erase failure rate information should contact their Renesas technical support representative.
- 8. -40°C for D version.
- 9. The data hold time includes time that the power supply is off or the clock is not supplied.

Table 5.10 High-speed On-Chip Oscillator Circuit Electrical Characteristics

Courada a l	Davarantas	Condition		Unit		
Symbol	Parameter	Condition	Min.	Тур.	Max.	Unit
fOCO40M	High-speed on-chip oscillator frequency temperature • supply voltage dependence	Vcc = 4.75 to 5.25 V $0^{\circ}C \leq T_{opr} \leq 60^{\circ}C^{(2)}$	39.2	40	40.8	MHz
		Vcc = 3.0 to 5.5 V -20°C \leq Topr \leq 85°C ⁽²⁾	38.8	40	41.2	MHz
		Vcc = 3.0 to 5.5 V -40°C \leq Topr \leq 85°C ⁽²⁾	38.4	40	41.6	MHz
		Vcc = 2.7 to 5.5 V -20°C \leq Topr \leq 85°C ⁽²⁾	38	40	42	MHz
		Vcc = 2.7 to 5.5 V -40°C \leq Topr \leq 85°C(2)	37.6	40	42.4	MHz
		Vcc = 2.2 to 5.5 V -20° C \leq Topr \leq 85 $^{\circ}$ C ⁽³⁾	35.2	40	44.8	MHz
		Vcc = 2.2 to 5.5 V -40°C \leq Topr \leq 85°C ⁽³⁾	34	40	46	MHz
		$Vcc = 5.0 V \pm 10\%$ -20°C \le Topr \le 85°C ⁽²⁾	38.8	40	40.8	MHz
		$Vcc = 5.0 V \pm 10\%$ -40°C \le Topr \le 85°C(2)	38.4	40	40.8	MHz
	High-speed on-chip oscillator frequency when	Vcc = 5.0 V, Topr = 25°C	-	36.864	_	MHz
	correction value in FRA7 register is written to FRA1 register ⁽⁴⁾	Vcc = 3.0 to 5.5 V -20°C \le Topr \le 85°C	-3%	-	3%	%
_	Value in FRA1 register after reset		08h ⁽³⁾	-	F7h ⁽³⁾	-
_	Oscillation frequency adjustment unit of high- speed on-chip oscillator	Adjust FRA1 register (value after reset) to -1	-	+0.3	-	MHz
_	Oscillation stability time		-	10	100	μS
_	Self power consumption at oscillation	Vcc = 5.0 V, Topr = 25°C	-	400	_	μΑ

- 1. Vcc = 2.2 to 5.5 V, $T_{opr} = -20$ to $85^{\circ}C$ (N version) / -40 to $85^{\circ}C$ (D version), unless otherwise specified.
- 2. These standard values show when the FRA1 register value after reset is assumed.
- 3. These standard values show when the corrected value of the FRA6 register is written to the FRA1 register.
- 4. This enables the setting errors of bit rates such as 9600 bps and 38400 bps to be 0% when the serial interface is used in UART mode.

Table 5.11 Low-speed On-Chip Oscillator Circuit Electrical Characteristics

Symbol	Parameter	Condition		Unit		
Symbol	Farameter	Condition	Min.	Тур.	Max.	Offic
fOCO-S	Low-speed on-chip oscillator frequency		30	125	250	kHz
_	Oscillation stability time		-	10	100	μS
_	Self power consumption at oscillation	Vcc = 5.0 V, Topr = 25°C	-	15	-	μА

NOTE:

1. Vcc = 2.2 to 5.5 V, $T_{opr} = -20$ to $85^{\circ}C$ (N version) / -40 to $85^{\circ}C$ (D version), unless otherwise specified.

Table 5.12 Power Supply Circuit Timing Characteristics

Symbol	Parameter	Condition		Standard			
Syllibol	Falametei	Condition	Min.	Тур.	Max.	Unit	
td(P-R)	Time for internal power supply stabilization during power-on ⁽²⁾		1	=	2000	μS	
td(R-S)	STOP exit time ⁽³⁾		=	=	150	μS	

- 1. The measurement condition is Vcc = 2.2 to 5.5 V and Topr = 25°C.
- 2. Waiting time until the internal power supply generation circuit stabilizes during power-on.
- 3. Time until system clock supply starts after the interrupt is acknowledged to exit stop mode.



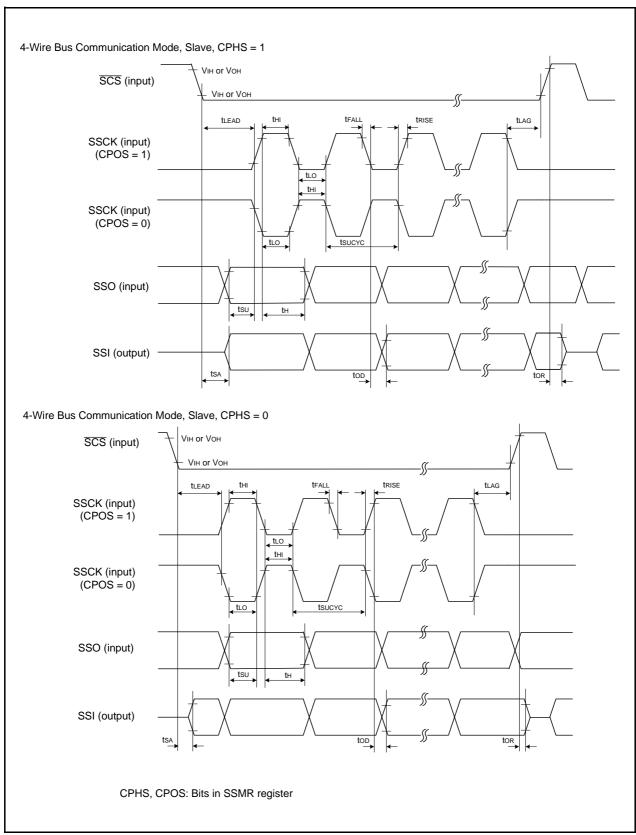


Figure 5.5 I/O Timing of Clock Synchronous Serial I/O with Chip Select (Slave)

Table 5.16 Electrical Characteristics (2) [Vcc = 5 V] (Topr = -20 to 85°C (N version) / -40 to 85°C (D version), unless otherwise specified.)

Symbol	Parameter	Condition			Standar	b	Unit
Symbol	Faiametei		Condition	Min.	Тур.	Max.	Offic
Icc	Power supply current (Vcc = 3.3 to 5.5 V) Single-chip mode, output pins are open,	High-speed clock mode	XIN = 20 MHz (square wave) High-speed on-chip oscillator off Low-speed on-chip oscillator on = 125 kHz No division	=	10	17	mA
	other pins are Vss		XIN = 16 MHz (square wave) High-speed on-chip oscillator off Low-speed on-chip oscillator on = 125 kHz No division	-	9	15	mA
			XIN = 10 MHz (square wave) High-speed on-chip oscillator off Low-speed on-chip oscillator on = 125 kHz No division	-	6	_	mA
			XIN = 20 MHz (square wave) High-speed on-chip oscillator off Low-speed on-chip oscillator on = 125 kHz Divide-by-8	-	5	_	mA
			XIN = 16 MHz (square wave) High-speed on-chip oscillator off Low-speed on-chip oscillator on = 125 kHz Divide-by-8	-	4	-	mA
			XIN = 10 MHz (square wave) High-speed on-chip oscillator off Low-speed on-chip oscillator on = 125 kHz Divide-by-8	-	2.5	-	mA
		High-speed on-chip oscillator mode	XIN clock off High-speed on-chip oscillator on fOCO = 20 MHz Low-speed on-chip oscillator on = 125 kHz No division	_	10	15	mA
			XIN clock off High-speed on-chip oscillator on fOCO = 20 MHz Low-speed on-chip oscillator on = 125 kHz Divide-by-8	_	4	_	mA
			XIN clock off High-speed on-chip oscillator on fOCO = 10 MHz Low-speed on-chip oscillator on = 125 kHz No division	_	5.5	10	mA
			XIN clock off High-speed on-chip oscillator on fOCO = 10 MHz Low-speed on-chip oscillator on = 125 kHz Divide-by-8	=	2.5	=	mA
		Low-speed on-chip oscillator mode	XIN clock off High-speed on-chip oscillator off Low-speed on-chip oscillator on = 125 kHz Divide-by-8, FMR47 = 1	-	130	300	μА
		Low-speed clock mode	XIN clock off High-speed on-chip oscillator off Low-speed on-chip oscillator off XCIN clock oscillator on = 32 kHz FMR47 = 1	-	130	300	μА
			XIN clock off High-speed on-chip oscillator off Low-speed on-chip oscillator off XCIN clock oscillator on = 32 kHz Program operation on RAM Flash memory off, FMSTP = 1	_	30	_	μА

Table 5.29 Electrical Characteristics (6) [Vcc = 2.2 V] (Topr = -20 to 85°C (N version) / -40 to 85°C (D version), unless otherwise specified.)

Symbol	Parameter	Condition		Standard			Unit
- y,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,	i didilictei			Min.	Тур.	Max.	Jiil
Power supply current (Vcc = 2.2 to 2.7 V) Single-chip mode, output pins are open, other pins are Vss	Single-chip mode,	High-speed clock mode	XIN = 5 MHz (square wave) High-speed on-chip oscillator off Low-speed on-chip oscillator on = 125 kHz No division	-	3.5		mA
		XIN = 5 MHz (square wave) High-speed on-chip oscillator off Low-speed on-chip oscillator on = 125 kHz Divide-by-8	_	1.5	_	mA	
		High-speed on-chip oscillator mode	XIN clock off High-speed on-chip oscillator on fOCO = 5 MHz Low-speed on-chip oscillator on = 125 kHz No division	_	3.5		mA
		mode	XIN clock off High-speed on-chip oscillator on fOCO = 5 MHz Low-speed on-chip oscillator on = 125 kHz Divide-by-8	_	1.5		mA
		Low-speed on-chip oscillator mode	XIN clock off High-speed on-chip oscillator off Low-speed on-chip oscillator on = 125 kHz Divide-by-8, FMR47 = 1	_	100	230	μА
		Low-speed clock mode	XIN clock off High-speed on-chip oscillator off Low-speed on-chip oscillator off XCIN clock oscillator on = 32 kHz FMR47 = 1	-	100	230	μА
			XIN clock off High-speed on-chip oscillator off Low-speed on-chip oscillator off XCIN clock oscillator on = 32 kHz Program operation on RAM Flash memory off, FMSTP = 1	-	25		μА
		Wait mode	XIN clock off High-speed on-chip oscillator off Low-speed on-chip oscillator on = 125 kHz While a WAIT instruction is executed Peripheral clock operation VCA27 = VCA26 = VCA25 = 0 VCA20 = 1	_	22	60	μА
			XIN clock off High-speed on-chip oscillator off Low-speed on-chip oscillator on = 125 kHz While a WAIT instruction is executed Peripheral clock off VCA27 = VCA26 = VCA25 = 0 VCA20 = 1	-	20	55	μА
			XIN clock off High-speed on-chip oscillator off Low-speed on-chip oscillator off XCIN clock oscillator on = 32 kHz (high drive) While a WAIT instruction is executed VCA27 = VCA26 = VCA25 = 0 VCA20 = 1	-	3.0	-	μА
			XIN clock off High-speed on-chip oscillator off Low-speed on-chip oscillator off XCIN clock oscillator on = 32 kHz (low drive) While a WAIT instruction is executed VCA27 = VCA26 = VCA25 = 0 VCA20 = 1	-	1.8	-	μА
		Stop mode	XIN clock off, Topr = 25°C High-speed on-chip oscillator off Low-speed on-chip oscillator off CM10 = 1 Peripheral clock off VCA27 = VCA26 = VCA25 = 0	=	0.7	3.0	μА
			XIN clock off, Topr = 85°C High-speed on-chip oscillator off Low-speed on-chip oscillator off CM10 = 1 Peripheral clock off VCA27 = VCA26 = VCA25 = 0	_	1.1	_	μА

J, K Version 5.2

Table 5.34 Absolute Maximum Ratings

Symbol	Parameter	Condition	Rated Value	Unit
Vcc/AVcc	Supply voltage		-0.3 to 6.5	V
Vı	Input voltage		-0.3 to Vcc + 0.3	V
Vo	Output voltage		-0.3 to Vcc + 0.3	V
Pd	Power dissipation	-40 °C ≤ Topr ≤ 85 °C	300	mW
		85 °C ≤ Topr ≤ 125 °C	125	mW
Topr	Operating ambient temperature		-40 to 85 (J version) / -40 to 125 (K version)	°C
Tstg	Storage temperature		-65 to 150	°C

Table 5.35 Recommended Operating Conditions

Symbol	Parameter		Conditions		Unit		
Symbol			Conditions	Min.	Тур.	Max.	Unit
Vcc/AVcc	Supply voltage			2.7	_	5.5	V
Vss/AVss	Supply voltage			-	0	_	V
ViH	Input "H" voltage			0.8 Vcc	_	Vcc	V
VIL	Input "L" voltage			0	_	0.2 Vcc	V
IOH(sum)	Peak sum output "H" current	Sum of all pins IOH(peak)		_	-	-60	mA
IOH(peak)	Peak output "H" current			-	=	-10	mA
IOH(avg)	Average output "H" current			-	=	-5	mA
IOL(sum)	Peak sum output "L" currents	Sum of all pins IOL(peak)		_	-	60	mA
IOL(peak)	Peak output "L" currents			_	-	10	mA
IOL(avg)	Average output "L" current			_	-	5	mA
f(XIN)	XIN clock input os	cillation frequency	3.0 V ≤ Vcc ≤ 5.5 V (other than K version)	0	=	20	MHz
			3.0 V ≤ Vcc ≤ 5.5 V (K version)	0	_	16	MHz
			2.7 V ≤ Vcc < 3.0 V	0	_	10	MHz
=	System clock	OCD2 = 0 XIN clock selected	3.0 V ≤ Vcc ≤ 5.5 V (other than K version)	0	=	20	MHz
			3.0 V ≤ Vcc ≤ 5.5 V (K version)	0	_	16	MHz
			2.7 V ≤ Vcc < 3.0 V	0	_	10	MHz
		OCD2 = 1 On-chip oscillator clock selected	FRA01 = 0 Low-speed on-chip oscillator clock selected	-	125	=	kHz
			FRA01 = 1 High-speed on-chip oscillator clock selected (other than K version)		-	20	MHz
			FRA01 = 1 High-speed on-chip oscillator clock selected	-	_	10	MHz

- 1. Vcc = 2.7 to 5.5 V at $T_{opr} = -40$ to $85^{\circ}C$ (J version) / -40 to $125^{\circ}C$ (K version), unless otherwise specified.
- 2. The average output current indicates the average value of current measured during 100 ms.

Table 5.42 High-speed On-Chip Oscillator Circuit Electrical Characteristics

Symbol	Parameter	Condition		Unit			
Syllibol	Farameter	Condition	Min.	Тур.	Max.	Onit	
fOCO40M	High-speed on-chip oscillator frequency temperature · supply voltage dependence	Vcc = 4.75 to 5.25 V $0^{\circ}C \leq Topr \leq 60^{\circ}C^{(2)}$	39.2	40	40.8	MHz	
		Vcc = 3.0 to 5.5 V -20°C \leq Topr \leq 85°C ⁽²⁾	38.8	40	41.2	MHz	
		Vcc = 3.0 to 5.5 V -40°C \leq Topr \leq 85°C ⁽²⁾	38.4	40	41.6	MHz	
		Vcc = 3.0 to 5.5 V -40°C \leq Topr \leq 125°C ⁽²⁾	38	40	42	MHz	
		Vcc = 2.7 to 5.5 V -40°C \leq Topr \leq 125°C(2)	37.6	40	42.4	MHz	
_	Value in FRA1 register after reset		08h	-	F7h	_	
=	Oscillation frequency adjustment unit of high- speed on-chip oscillator	Adjust FRA1 register (value after reset) to -1	=	+0.3	=	MHz	
_	Oscillation stability time		-	10	100	μS	
_	Self power consumption at oscillation	Vcc = 5.0 V, Topr = 25°C	-	400	-	μΑ	

- 1. Vcc = 2.7 to 5.5 V, Topr = -40 to $85^{\circ}C$ (J version) / -40 to $125^{\circ}C$ (K version), unless otherwise specified.
- 2. These standard values show when the FRA1 register value after reset is assumed.

Table 5.43 Low-speed On-Chip Oscillator Circuit Electrical Characteristics

Symbol	Parameter	Condition		Unit		
Symbol	Falametei	Condition		Тур.	Max.	Offic
fOCO-S	Low-speed on-chip oscillator frequency		40	125	250	kHz
_	Oscillation stability time		-	10	100	μS
_	Self power consumption at oscillation	Vcc = 5.0 V, Topr = 25°C	_	15	_	μА

NOTE:

Table 5.44 Power Supply Circuit Timing Characteristics

Svmbol	Parameter	Condition	,	Unit		
Symbol	Falametei	Condition		Тур.	Max.	Offic
td(P-R)	Time for internal power supply stabilization during power-on ⁽²⁾		1	=	2000	μS
td(R-S)	STOP exit time ⁽³⁾		-	-	150	μS

- 1. The measurement condition is Vcc = 2.7 to 5.5 V and T_{opr} = 25°C.
- 2. Waiting time until the internal power supply generation circuit stabilizes during power-on.
- 3. Time until system clock supply starts after the interrupt is acknowledged to exit stop mode.

^{1.} Vcc = 2.7 to 5.5 V, Topr = -40 to 85°C (J version) / -40 to 125°C (K version), unless otherwise specified.

Table 5.45 Timing Requirements of Clock Synchronous Serial I/O with Chip Select(1)

Cumbal	Parameter		Conditions Min.		Stand	Unit	
Symbol					Тур. Мах.		
tsucyc	SSCK clock cycle tim	е		4	-	-	tcyc(2)
tHI	SSCK clock "H" width			0.4	-	0.6	tsucyc
tLO	SSCK clock "L" width			0.4	_	0.6	tsucyc
trise	SSCK clock rising	Master		=	=	1	tcyc(2)
	time	Slave		=	_	1	μS
tfall	SSCK clock falling	Master		-	-	1	tcyc(2)
	time	Slave		=	_	1	μS
tsu	SSO, SSI data input s	etup time		100	-	-	ns
tH	SSO, SSI data input h	old time		1	=	-	tcyc(2)
tLEAD	SCS setup time	Slave		1tcyc + 50	-	-	ns
tLAG	SCS hold time	Slave		1tcyc + 50	=	-	ns
top	SSO, SSI data output delay time			_	-	1	tcyc(2)
tsa	SSI slave access time			-	_	1.5tcyc + 100	ns
tor	SSI slave out open tir	ne		_	_	1.5tcyc + 100	ns

- 1. Vcc = 2.7 to 5.5 V, Vss = 0 V at $T_{opr} = -40$ to $85^{\circ}C$ (J version) / -40 to $125^{\circ}C$ (K version), unless otherwise specified. 2. 1tCyc = 1/f1(s)

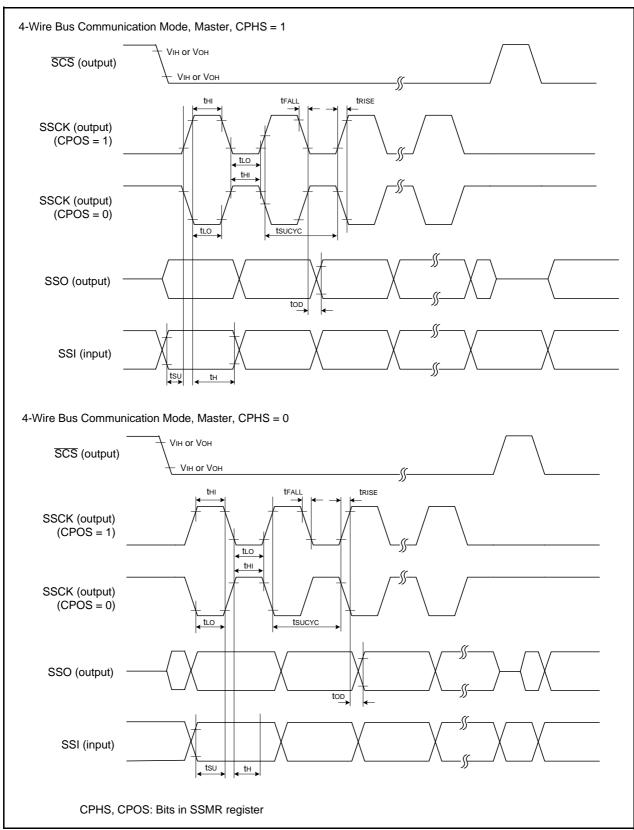


Figure 5.23 I/O Timing of Clock Synchronous Serial I/O with Chip Select (Master)

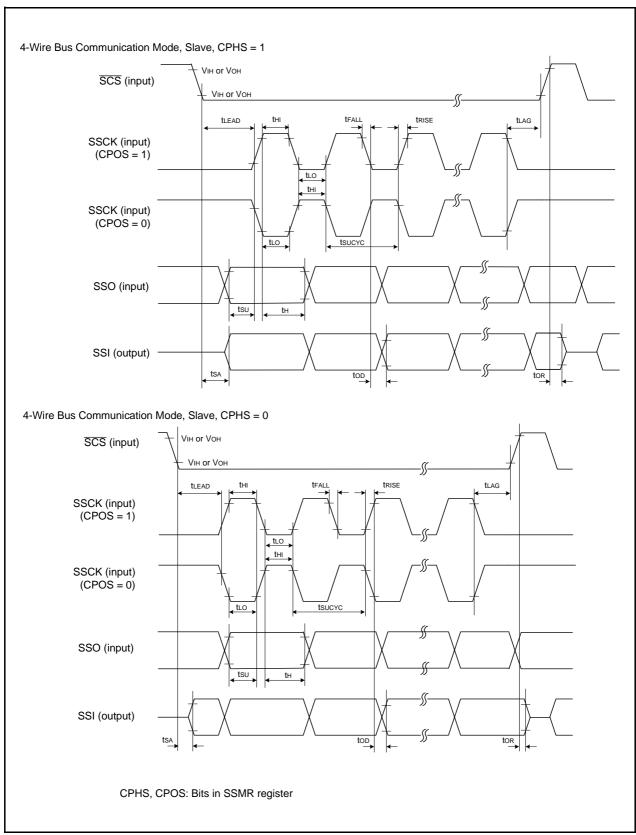


Figure 5.24 I/O Timing of Clock Synchronous Serial I/O with Chip Select (Slave)

Table 5.53 Electrical Characteristics (3) [Vcc = 3 V]

Symbol	Pare	ameter	Condi	ition	Si	Unit		
Symbol	i didilielei		Cond	Condition			Тур.	Max.
Vон	Output "H" voltage	Except XOUT	Iон = -1 mA		Vcc - 0.5	-	Vcc	V
		XOUT	Drive capacity HIGH	Iон = -0.1 mA	Vcc - 0.5	_	Vcc	V
			Drive capacity LOW	Іон = -50 μΑ	Vcc - 0.5	=	Vcc	V
Vol	Output "L" voltage	Except XOUT	IoL = 1 mA		_	-	0.5	V
		XOUT	Drive capacity HIGH	IoL = 0.1 mA	=	=	0.5	V
			Drive capacity LOW	IOL = 50 μA	=	=	0.5	V
VT+-VT-	Hysteresis	INTO, INT1, INT3, KIO, KI1, KI2, KI3, TRAIO, RXDO, RXD1, CLKO,CLK1, SSI, SCL, SDA, SSO			0.1	0.3	-	V
		RESET			0.1	0.4	_	V
Іін	Input "H" current	1	VI = 3 V, Vcc = 3	V	_	-	4.0	μΑ
lıL	Input "L" current		VI = 0 V, Vcc = 3V		_	-	-4.0	μΑ
RPULLUP	Pull-up resistance		VI = 0 V, Vcc = 3'	V	66	160	500	kΩ
RfXIN	Feedback resistance	XIN			-	3.0	_	MΩ
VRAM	RAM hold voltage	•	During stop mode	Э	2.0	_	_	V

^{1.} Vcc = 2.7 to 3.3 V at Topr = -40 to 85°C (J version) / -40 to 125°C (K version), f(XIN) = 10 MHz, unless otherwise specified.

Table 5.54 Electrical Characteristics (4) [Vcc = 3 V] (Topr = -40 to 85°C (J version) / -40 to 125°C (K version), unless otherwise specified.)

Symbol	Parameter	Parameter Condition		;	Unit		
Symbol	Faiailielei		Condition	Min.	Тур.	Max.	UIIIL
Icc	Power supply current (Vcc = 2.7 to 3.3 V) Single-chip mode, output pins are open,	High-speed clock mode	XIN = 10 MHz (square wave) High-speed on-chip oscillator off Low-speed on-chip oscillator on = 125 kHz No division	-	6	-	mA
	other pins are Vss		XIN = 10 MHz (square wave) High-speed on-chip oscillator off Low-speed on-chip oscillator on = 125 kHz Divide-by-8	-	2	=	mA
		High-speed on-chip oscillator mode	XIN clock off High-speed on-chip oscillator on fOCO = 10 MHz Low-speed on-chip oscillator on = 125 kHz No division	-	5	9	mA
			XIN clock off High-speed on-chip oscillator on fOCO = 10 MHz Low-speed on-chip oscillator on = 125 kHz Divide-by-8	Ι	2	-	mA
		Low-speed on-chip oscillator mode	XIN clock off High-speed on-chip oscillator off Low-speed on-chip oscillator on = 125 kHz Divide-by-8, FMR47 = 1	I	130	300	μА
		Wait mode	XIN clock off High-speed on-chip oscillator off Low-speed on-chip oscillator on = 125 kHz While a WAIT instruction is executed Peripheral clock operation VCA27 = VCA26 = VCA25 = 0 VCA20 = 1		25	70	μА
			XIN clock off High-speed on-chip oscillator off Low-speed on-chip oscillator on = 125 kHz While a WAIT instruction is executed Peripheral clock off VCA27 = VCA26 = VCA25 = 0 VCA20 = 1	-	23	55	μА
		Stop mode	XIN clock off, Topr = 25°C High-speed on-chip oscillator off Low-speed on-chip oscillator off CM10 = 1 Peripheral clock off VCA27 = VCA26 = VCA25 = 0	=	0.7	3.0	μА
			XIN clock off, Topr = 85°C High-speed on-chip oscillator off Low-speed on-chip oscillator off CM10 = 1 Peripheral clock off VCA27 = VCA26 = VCA25 = 0	I	1.1	_	μА
			XIN clock off, Topr = 125°C High-speed on-chip oscillator off Low-speed on-chip oscillator off CM10 = 1 Peripheral clock off VCA27 = VCA26 = VCA25 = 0	-	3.8	_	μА

Timing requirements

(Unless Otherwise Specified: Vcc = 3 V, Vss = 0 V at Topr = 25°C) [Vcc = 3 V]

Table 5.55 XIN Input

Symbol	Parameter		Standard		
Symbol			Max.	Unit	
tc(XIN)	XIN input cycle time	100	=	ns	
twh(xin)	XIN input "H" width	40	=	ns	
tWL(XIN)	XIN input "L" width	40	=	ns	

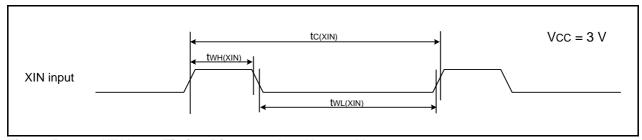


Figure 5.31 XIN Input Timing Diagram when Vcc = 3 V

Table 5.56 TRAIO Input

Symbol	Parameter		Standard		
Symbol			Max.	Unit	
tc(TRAIO)	TRAIO input cycle time	300	-	ns	
tWH(TRAIO)	TRAIO input "H" width	120	=	ns	
twl(traio)	TRAIO input "L" width	120	=	ns	

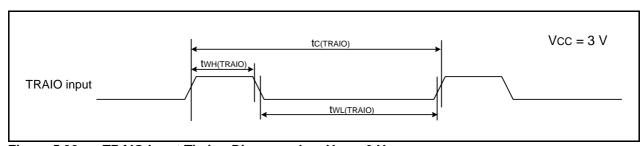
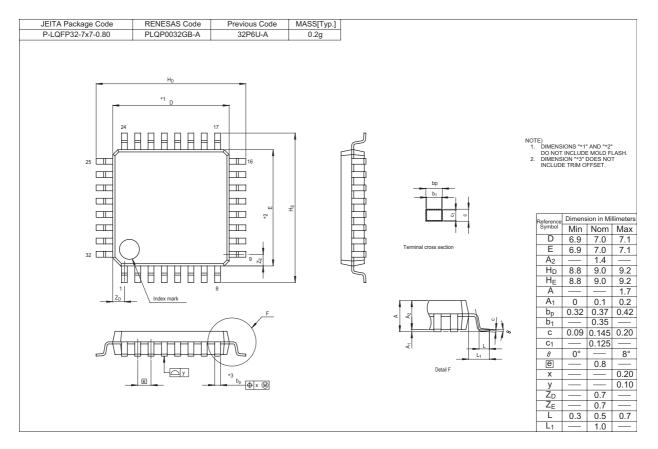


Figure 5.32 TRAIO Input Timing Diagram when Vcc = 3 V

Package Dimensions

Diagrams showing the latest package dimensions and mounting information are available in the "Packages" section of the Renesas Technology website.



REVISION HISTORY

R8C/26 Group, R8C/27 Group Datasheet

	5.4		Description
Rev.	Date	Page	Summary
0.10	Nov 14, 2005	-	First edition issued
0.20	Feb 06, 2006	2, 3	Table 1.1 Functions and Specifications for R8C/26Group and Table 1.2 Functions and Specifications for R8C/27 Group; Minimum instruction execution time and Supply voltage revised
		9	Table 1.6 Pin Name Information by Pin Number; "XOUT" \rightarrow "XOUT/XCOUT" and "XIN" \rightarrow "XIN/XCIN" revised
		18	Table 4.4 SFR Information (4); 00FEh: "DRR" → "P1DRR" revised
		19	Table 4.5 SFR Information (5); -0119h: "Timer RE Minute Data Register / Compare Register" → "Timer RE Minute Data Register / Compare Data Register" -011Ah: "Timer RE Time Data Register" → "Timer RE Hour Data Register" -011Bh: "Timer RE Day Data Register" → "Timer RE Day of Week Data Register" revised
		22 to 45	5. Electrical Characteristics added
1.00	Nov 08, 2006	All pages	"Preliminary" deleted
		2	Table 1.1 revised
		3	Table 1.2 revised
		4	Figure 1.1 revised
		5	Table 1.3 revised
		6	Table 1.4 revised
		7	Figure 1.4 revised
		9	Table 1.6 revised
		15	Table 4.1;
			 • 001Ch: "00h" → "00h, 10000000b" revised • 000Fh: "000XXXXXb" → "00X11111b" revised • 0029h: "High-Speed On-Chip Oscillator Control Register 4, FRA4, When shipping" added • 002Bh: "High-Speed On-Chip Oscillator Control Register 6, FRA6, When shipping" added • 0032h: "00h, 01000000b" → "00h, 00100000b" revised • 0038h: "00001000b, 01001001b" → "0000X000b, 0100X001b" revised • NOTE3 and 4 revised; NOTE6 added
		18	Table 4.4; • 00E0h, 00E1h, 00E5h, 00E8h, 00E9h: "XXh" → "00h" revised • 00FDh: "XX00000000b" → "00h" revised
		22	Table 5.2 revised
		23	Figure 5.1 title revised
		24	Table 5.4 revised
		25	Table 5.5 revised
		26	Figure 5.2 title revised and Table 5.7 NOTE4 added